## NSN 5961-00-976-3332

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-976-3332 **Inclosure Material:** Glass **Overall Length:** 0.375 inches **Terminal Length:** 1.250 inches **Overall Diameter:** 0.200 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.2 reverse voltage, peak **Current Rating Per Characteristic:** 2.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

No Fiig: A110a0